



# 0.5Ω、四路 SPDT 开关，UCSP/QFN 封装

MAX4754/MAX4755/MAX4756

## 概述

MAX4754/MAX4755/MAX4756 是低导通电阻模拟开关，采用 +1.8V 至 +5.5V 单电源供电。MAX4754 和 MAX4755 是双路、双刀双掷 (DPDT) 开关。MAX4756 是四路、单刀双掷 (SPDT) 开关。这些器件可以配置用来切换音频或数据信号。

MAX4754 有四个 0.5Ω 的 SPDT 开关，用于音频信号切换，并有两个逻辑控制输入。MAX4755 有四个 0.5Ω 的 SPDT 开关（两个开关分别在 NC 端加有额外的 11Ω 串联电阻）。这样用户可以将 8Ω 扬声器当作 32Ω 负载（耳机扬声器）来驱动。MAX4756 有四个 0.5Ω 的 SPDT 开关，这些开关由一个逻辑控制输入和一个使能引脚控制，使能引脚 (EN) 可用来禁止这些开关。

MAX4754/MAX4755/MAX4756 提供节省空间的 16 引脚、薄型 QFN 封装和微型、16 焊球、2mm x 2mm 晶片级封装 (UCSP™)。

## 应用

- 扬声器-耳机开关
- 音频信号切换
- 蜂窝电话
- PDA/手持式设备
- 笔记本电脑

## 特性

- ◆ 数据与音频信号切换
- ◆ 低  $R_{ON}$  (0.5Ω) 音频开关
- ◆ 0.1Ω 通道间匹配度
- ◆ 0.2Ω 导通电阻平坦度
- ◆ 0.02% THD
- ◆ +1.8V 至 +5.5V 电源范围
- ◆ 可处理满摆幅信号
- ◆ 16 焊球 UCSP (2mm x 2mm) 封装

## 订购信息

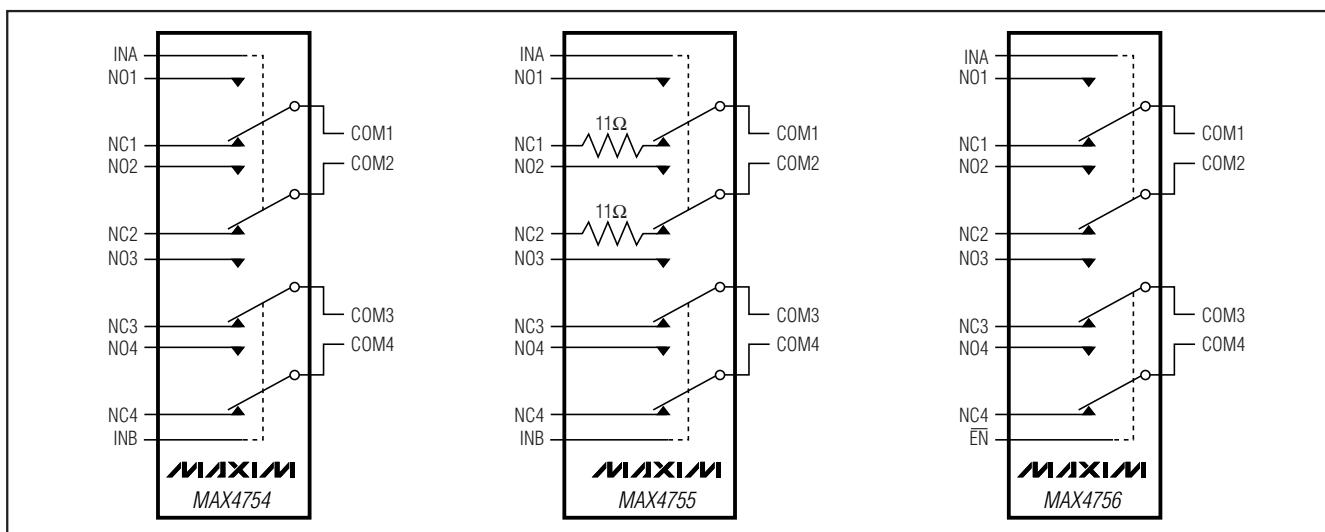
PART	TEMP RANGE	PIN-PACKAGE
<b>MAX4754EBE-T</b>	-40°C to +85°C	16 UCSP-16
MAX4754ETE	-40°C to +85°C	16 Thin QFN (4mm x 4mm)
<b>MAX4755EBE-T*</b>	-40°C to +85°C	16 UCSP-16
MAX4755ETE*	-40°C to +85°C	16 Thin QFN (4mm x 4mm)
<b>MAX4756EBE-T*</b>	-40°C to +85°C	16 UCSP-16
MAX4756ETE*	-40°C to +85°C	16 Thin QFN (4mm x 4mm)

\* 未来产品—供货情况请联系厂商

引脚配置在数据资料的最后部分给出。

UCSP 是 Maxim Integrated Products, Inc. 的商标。

## 功能框图



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## ABSOLUTE MAXIMUM RATINGS

(All Voltages Referenced to GND)

V+, IN_, EN.....	-0.3V to +6V
COM_, NO_, NC_ (Note 1) .....	-0.3V to (V+ + 0.3V)
Continuous Current	
NC1, NC2, COM1, COM2 (MAX4755).....	±100mA
NO_, NC_, COM_ (remaining terminal connections) .....	±300mA
Peak Current NC1, NC2, COM1, COM2 (MAX4755)	
(Pulsed at 1ms, 10% duty cycle).....	±200mA
(Pulsed at 1ms, 50% duty cycle).....	±150mA
Peak Current NO_, NC_,	
COM_ (remaining terminal connections)	
(Pulsed at 1ms, 10% duty cycle).....	±500mA
(Pulsed at 1ms, 50% duty cycle).....	±400mA

**Note 1:** Signals on NO\_, NC\_, COM\_ exceeding V+ or GND are clamped by internal diodes. Limit forward-diode current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## ELECTRICAL CHARACTERISTICS

(V+ = +2.7V to +5.25V, TA = -40°C to +85°C, unless otherwise noted. Typical values are at +3V and TA = +25°C.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS		TA	MIN	TYP	MAX	UNITS
<b>ANALOG SWITCH</b>								
Analog Signal Range	V <sub>COM_</sub> , V <sub>NO_</sub> , V <sub>NC_</sub>			T <sub>MIN</sub> to T <sub>MAX</sub>	0	V+		V
On-Resistance	R <sub>ON</sub>	V+ = 2.7V, I <sub>COM_</sub> = 10mA, V <sub>NC_</sub> = 0V, or V <sub>NC_</sub> = V+ (Note 4)	MAX4755 (NO1, NO2, N <sub>3</sub> , N <sub>4</sub> ), MAX4754/MAX4756	+25°C	0.5	0.85		Ω
			MAX4755 (NC1, NC2)	T <sub>MIN</sub> to T <sub>MAX</sub>		1.0		
				+25°C	11.5			
				T <sub>MIN</sub> to T <sub>MAX</sub>	8.0	12.5		
On-Resistance Match Between Channels	ΔR <sub>ON</sub>	V+ = 2.7V, I <sub>COM_</sub> = 10mA, V <sub>NO_</sub> = 1.5V, or V <sub>NC_</sub> = 1.5V (Notes 4, 5)	MAX4755 (NO1, NO2, N <sub>3</sub> , N <sub>4</sub> ) MAX4754/MAX4756	+25°C	0.1	0.35		Ω
			MAX4755 (NC1, NC2)	T <sub>MIN</sub> to T <sub>MAX</sub>		0.55		
				+25°C	0.2	0.4		
				T <sub>MIN</sub> to T <sub>MAX</sub>		0.55		
On-Resistance Flatness	R <sub>FLAT(ON)</sub>	V+ = 3V, I <sub>COM_</sub> = 10mA, V <sub>NO_</sub> = 0V, or V <sub>NC_</sub> = V+ (Note 6)	MAX4755 (NO1, NO2, N <sub>3</sub> , N <sub>4</sub> ), NO1, NO2, MAX4754/MAX4756	+25°C	0.2	0.4		Ω
				T <sub>MIN</sub> to T <sub>MAX</sub>		0.55		
NO_, NC_ Off-Leakage Current	I <sub>NO_(OFF)</sub> , I <sub>NC_(OFF)</sub>	V+ = 3.6V; V <sub>COM_</sub> = 3.3V, 0.3V; V <sub>NO_</sub> or V <sub>NC_</sub> = 0.3V, 3.3V	+25°C	-3		+3		nA
			T <sub>MIN</sub> to T <sub>MAX</sub>	-10		+10		
COM_ Off-Leakage Current	I <sub>COM_(OFF)</sub>	V+ = 3.6V (MAX4756); V <sub>COM_</sub> = 3.3V, 0.3V; V <sub>NO_</sub> or V <sub>NC_</sub> = 0.3V, 3.3V	+25°C	-3	±0.01	+3		nA
			T <sub>MIN</sub> to T <sub>MAX</sub>	-10		+10		

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## ELECTRICAL CHARACTERISTICS (Continued)

( $V_+ = +2.7V$  to  $+5.25V$ ,  $T_A = -40^\circ C$  to  $+85^\circ C$ , unless otherwise noted. Typical values are at  $+3V$  and  $T_A = +25^\circ C$ .) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP	MAX	UNITS
COM_On-Leakage Current	I <sub>COM_(ON)</sub>	$V_+ = 3.6V$ ; $V_{COM\_} = 3.3V, 0.3V$ ; $V_{NO\_}$ or $V_{NC\_} = 3.3V, 0.3V$ or floating	+25°C	-3		+3	nA
			T <sub>MIN</sub> to T <sub>MAX</sub>	-10		+10	
<b>DYNAMIC</b>							
Turn-On Time	t <sub>ON</sub>	$V_+ = 2.7V, V_{NO\_}$ or $V_{NC\_} = 1.5V$ ; $R_L = 50\Omega$ ; $C_L = 35pF$ , Figure 1	+25°C	45	140	ns	
			T <sub>MIN</sub> to T <sub>MAX</sub>		150		
Turn-Off Time	t <sub>OFF</sub>	$V_+ = 2.7V, V_{NO\_}$ or $V_{NC\_} = 1.5V$ ; $R_L = 50\Omega$ ; $C_L = 35pF$ , Figure 1	+25°C	25	50	ns	
			T <sub>MIN</sub> to T <sub>MAX</sub>		60		
Break-Before-Make	t <sub>BBM</sub>	$V_+ = 2.7V, V_{NO\_}$ or $V_{NC\_} = 1.5V$ ; $R_L = 50\Omega$ , $C_L = 35pF$ , Figure 2 (Note 7)	+25°C	15	ns		
			T <sub>MIN</sub> to T <sub>MAX</sub>	2			
Charge Injection	Q	$V_{GEN} = 0V, R_{GEN} = 0, C_L = 1.0nF$ , Figure 3	+25°C	50		pC	
On-Channel -3dB Bandwidth	BW	Signal = 0dBm, $C_L = 50pF, R_L = 50\Omega$ ,	+25°C	325		MHz	
Off-Isolation	V <sub>ISO</sub>	$C_L = 5pF, R_L = 50\Omega, V_{COM\_} = 1V_{P-P}$ $f = 100kHz$ , Figure 4 (Note 8)	+25°C	-120		dB	
Crosstalk	V <sub>CT</sub>	$C_L = 5pF, R_L = 50\Omega, V_{COM\_} = 1V_{P-P}$ $f = 100kHz$ , Figure 4 (Note 9)	+25°C	-120		dB	
Total Harmonic Distortion	THD	$f = 20Hz$ to $20kHz, 1V_{P-P}$ , $R_L = 32\Omega$	+25°C	0.02		%	
NO_, NC_Off-Capacitance	C <sub>NO_(OFF)</sub> , C <sub>NC_(OFF)</sub>	$V_{NO}, V_{NC\_} = GND$ , $f = 1MHz, V_{COM\_} = 0.5V_{P-P}$ , Figure 5	+25°C	65		pF	
COM_Off-Capacitance	C <sub>COM_(OFF)</sub>	$V_{COM\_} = GND, f = 1MHz$ , MAX4756, Figure 5	+25°C	110		pF	
COM_On-Capacitance	C <sub>(ON)</sub>	$V_{COM\_} = V_{NO}, V_{NC\_} = GND, f = 1MHz$ , $V_{COM\_} = 0.5V_{P-P}$ , Figure 5	+25°C	168		pF	
<b>DIGITAL I/O (IN_, EN)</b>							
Input Logic High	V <sub>IH</sub>	$V_+ = 2.7V$ to $3.6V$	T <sub>MIN</sub> to T <sub>MAX</sub>	1.4		V	
		$V_+ = 3.6V$ to $5.25V$	T <sub>MIN</sub> to T <sub>MAX</sub>	2.0			
Input Logic Low	V <sub>IL</sub>	$V_+ = 2.7V$ to $3.6V$	T <sub>MIN</sub> to T <sub>MAX</sub>		0.5	V	
		$V_+ = 3.6V$ to $5.25V$	T <sub>MIN</sub> to T <sub>MAX</sub>		0.6		
Input Leakage Current	I <sub>IN</sub>	$V_{IN} = 0V$ or $V_+$	T <sub>MIN</sub> to T <sub>MAX</sub>		1	μA	

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## ELECTRICAL CHARACTERISTICS (Continued)

( $V_+ = +2.7V$  to  $+5.25V$ ,  $T_A = -40^\circ C$  to  $+85^\circ C$ , unless otherwise noted. Typical values are at  $+3V$  and  $T_A = +25^\circ C$ .) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP	MAX	UNITS
<b>POWER SUPPLY</b>							
Power-Supply Range	$V_+$		$T_{MIN}$ to $T_{MAX}$	1.8		5.5	V
Positive-Supply Current	$I_+$	$V_+ = 5.5V$ , $V_{IN\_} = 0V$ or $V_+$	$+25^\circ C$		0.001		$\mu A$
			$T_{MIN}$ to $T_{MAX}$			1.0	

**Note 2:** The algebraic convention is used in this data sheet; the most negative value is shown in the minimum column.

**Note 3:** UCSP parts are 100% tested at  $+25^\circ C$  and limits across the full temperature range are guaranteed by correlation and design. Thin QFN parts are 100% tested at  $+85^\circ C$  and limits across the full temperature range are guaranteed by correlation and design.

**Note 4:**  $R_{ON}$  and  $\Delta R_{ON}$  matching specifications are guaranteed by design.

**Note 5:**  $\Delta R_{ON} = R_{ON(MAX)} - R_{ON(MIN)}$ .

**Note 6:** Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal ranges.

**Note 7:** Guaranteed by design, not production tested.

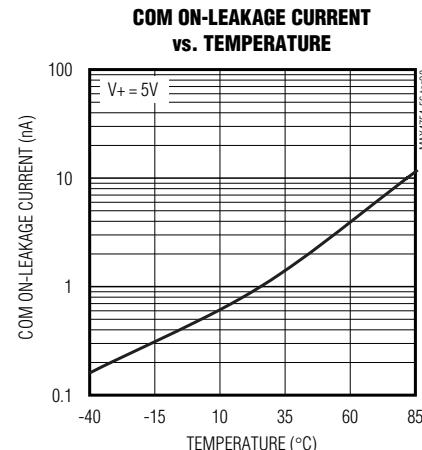
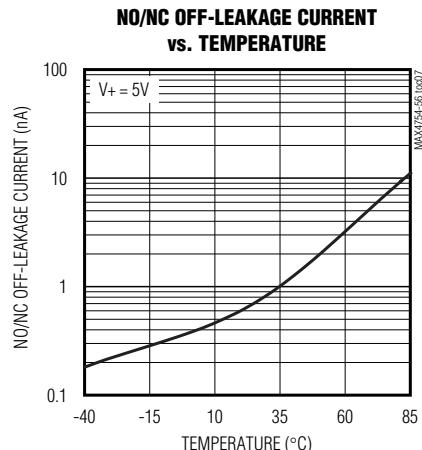
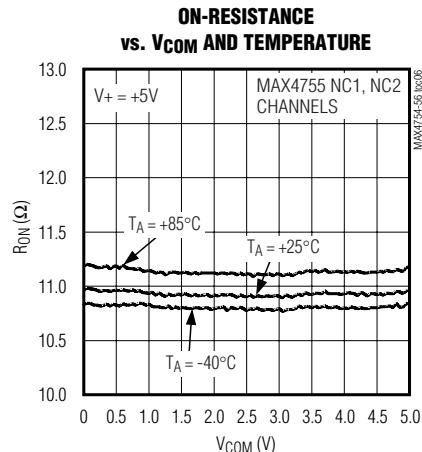
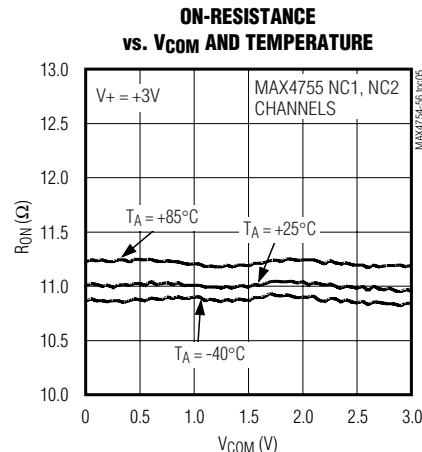
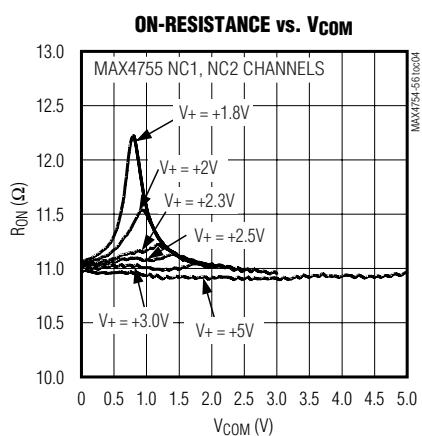
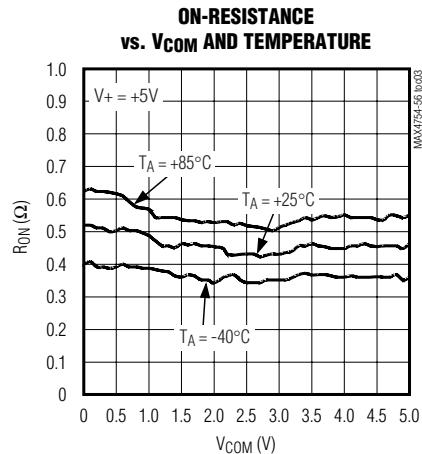
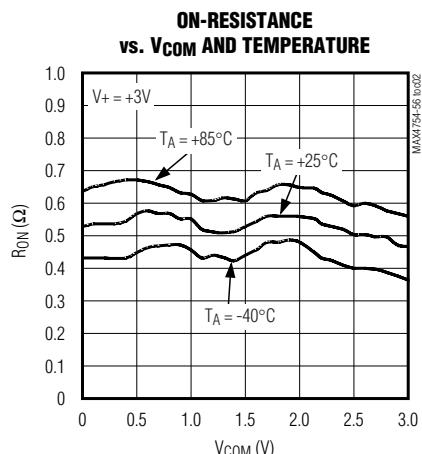
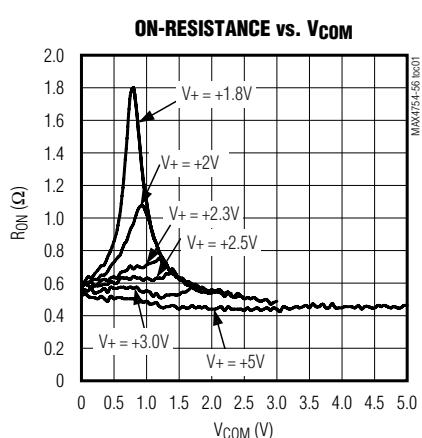
**Note 8:** Off-Isolation =  $20\log_{10} [V_{COM} / (V_{NO} \text{ or } V_{NC})]$ ,  $V_{COM}$  = output,  $V_{NO}$  or  $V_{NC}$  = input to off switch.

**Note 9:** Between any two switches.

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## 典型工作特性

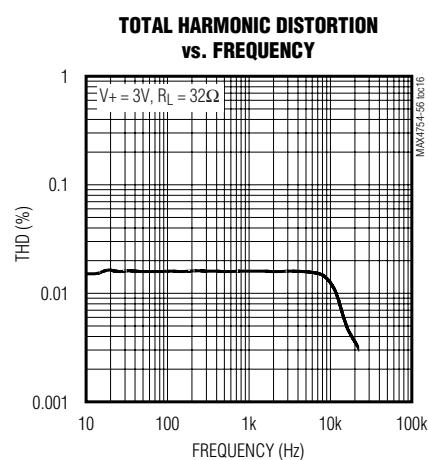
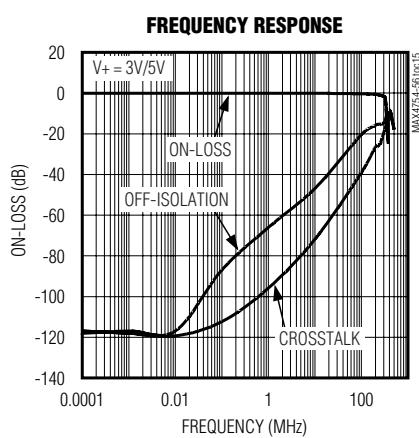
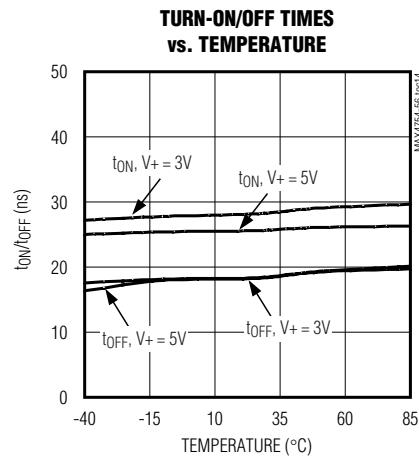
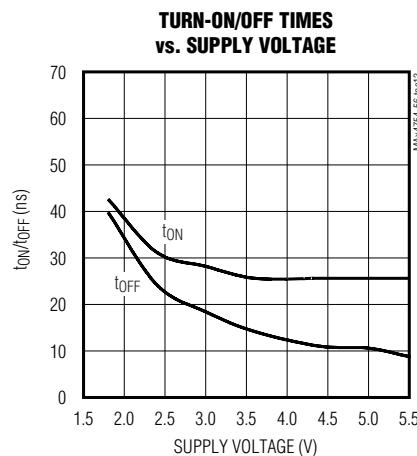
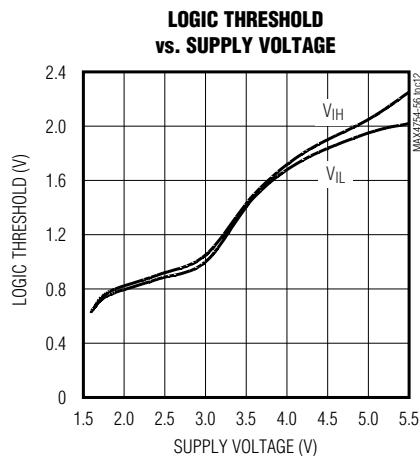
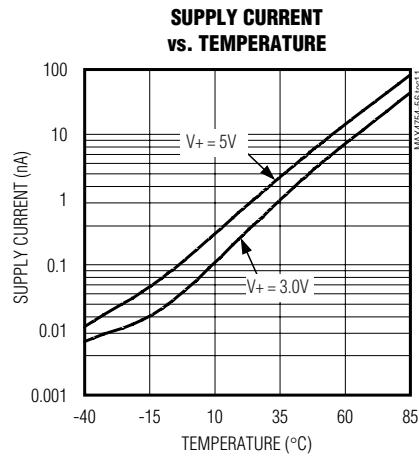
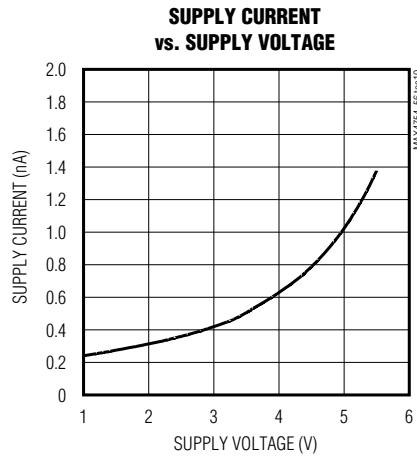
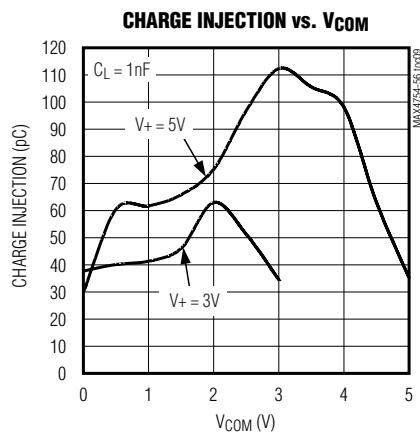
( $V_+ = 3V$ ,  $T_A = +25^\circ C$ , unless otherwise noted.)



# 0.5Ω、四路SPDT开关，UCSP/QFN封装

## 典型工作特性(续)

( $V_+ = 3V$ ,  $T_A = +25^\circ C$ , unless otherwise noted.)

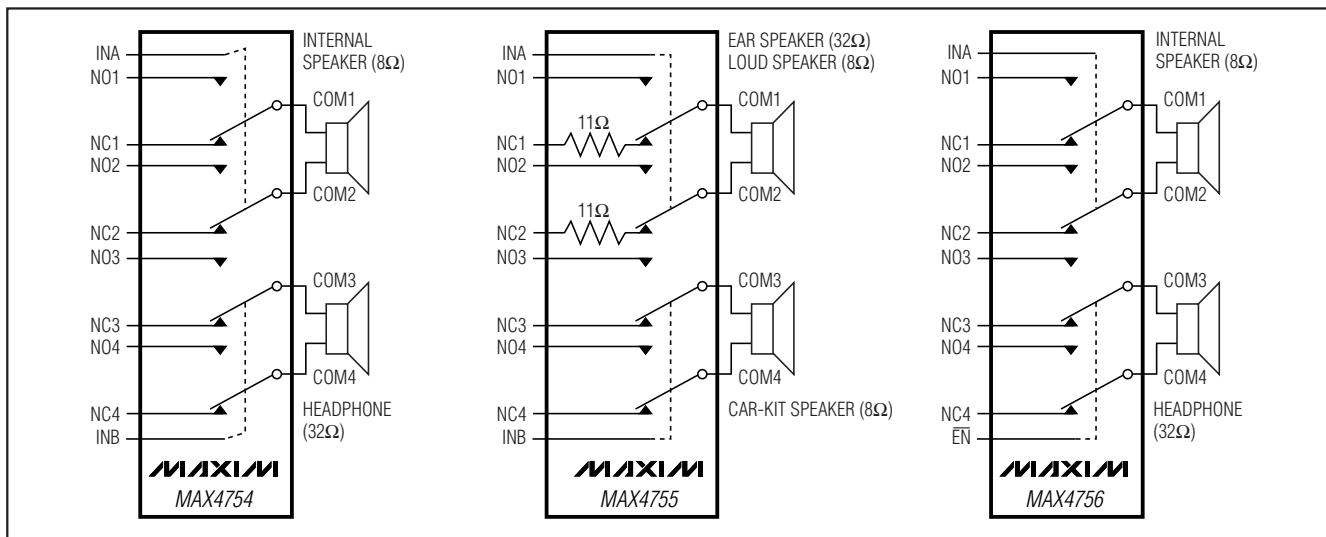


# 0.5Ω、四路SPDT开关，UCSP/QFN封装

## 引脚说明

引脚						名称	功能		
MAX4754		MAX4755		MAX4756					
UCSP	QFN	UCSP	QFN	UCSP	QFN				
C1	1	C1	1	C1	1	NO1	模拟开关1，常开端1。		
C2	2	C2	2	C2	2	INA	开关1和2的逻辑控制数字输入。MAX4756中开关1-4的数控输入。		
B1	3	B1	3	B1	3	COM1	模拟开关1，公共端1。		
A1	4	A1	4	A1	4	NC1	模拟开关1，常闭端1。		
A2	5	A2	5	A2	5	NO4	模拟开关4，常开端4。		
B2	6	B2	6	B2	6	V+	正电源输入		
A3	7	A3	7	A3	7	COM4	模拟开关4，公共端4。		
A4	8	A4	8	A4	8	NC4	模拟开关4，常闭端4。		
B4	9	B4	9	B4	9	NO2	模拟开关2，常开端2。		
B3	10	B3	10	—	—	INB	开关3和4的逻辑控制数字输入		
—	—	—	—	B3	10	EN	输出使能，低电平有效。		
C4	11	C4	11	C4	11	COM2	模拟开关2，公共端2。		
D4	12	D4	12	D4	12	NC2	模拟开关2，常闭端2。		
D3	13	D3	13	D3	13	NO3	模拟开关3，常开端3。		
C3	14	C3	14	C3	14	GND	地		
D2	15	D2	15	D2	15	COM3	模拟开关3，公共端3。		
D1	16	D1	16	D1	16	NC3	模拟开关3，常闭端3。		
—	PAD	—	PAD	—	PAD	EP	裸露焊盘，与GND相连。		

## 典型工作电路



# 0.5Ω、四路 SPDT 开关，UCSP/QFN 封装

## 详细说明

MAX4754/MAX4755/MAX4756 是低导通电阻模拟开关，采用 +1.8V 至 +5.5V 单电源供电。这些器件完全规范于电源标称值为 3V 的应用。

MAX4754 DPDT 开关有两个逻辑控制输入，每个输入控制两个 SPDT 开关。每个开关的 NO 和 NC 端的导通电阻为 0.5Ω，这使其非常适合音频信号切换。

MAX4755 DPDT 开关也有四个 0.5Ω 的 SPDT 开关，开关 1 和 2 的 NC 端还加有 11.5Ω 的串联电阻。该特性允许用户将 8Ω 扬声器当作 32Ω 负载来驱动，使之可以作为耳机扬声器来使用。使用两个逻辑控制输入控制四个开关。

MAX4756 有四个 0.5Ω 的 SPDT 开关，由一个逻辑控制输入(INA) 和一个 EN 输入来控制，EN 输入用来禁止开关。

## 应用信息

### 数控输入

无论采用何种电源电压，MAX4754/MAX4755/MAX4756 的逻辑输入端都可以承受最大 +5.5V 的电压。例如在 +3.3V 供电时，IN\_ 端可以低至 GND，也可以高至 +5.5V，这就允许混合逻辑电平共存于同一个系统中。满摆幅驱动控制逻辑输入可将功耗降至最低。在 +3V 电源电压下，逻辑电平门限值为 0.5V(低) 和 1.4V(高)。

对于 MAX4756，将 EN 驱动至低电平使能 COM\_。当 EN 为高电平时，COM\_ 为高阻状态。

## 模拟信号电平

整个供电电压范围内 (0V 到 V+) 的模拟信号输入都可通过开关，且导通电阻变化极小(见典型工作特性)。开关是双向的，因此 NO\_、NC\_ 和 COM\_ 既可作为输入也可作为输出。

## 电源旁路

电源旁路能够改善噪声容限，并能阻止开关噪声从 V+ 电源传播到其他器件。在 V+ 和 GND 之间连接一个 0.1μF 电容即可满足大多数应用的要求。

## UCSP 应用信息

关于 UCSP 结构、尺寸、载带信息、印刷电路板技术、焊盘布局、推荐的回流焊温度特性，以及可靠性测试结果的最新应用数据，可从 Maxim 网站 [www.maxim-ic.com.cn/ucsp](http://www.maxim-ic.com.cn/ucsp) 下载应用笔记：UCSP—晶片级封装。

## 0.5Ω、四路SPDT开关，UCSP/QFN封装

测试电路/时序图

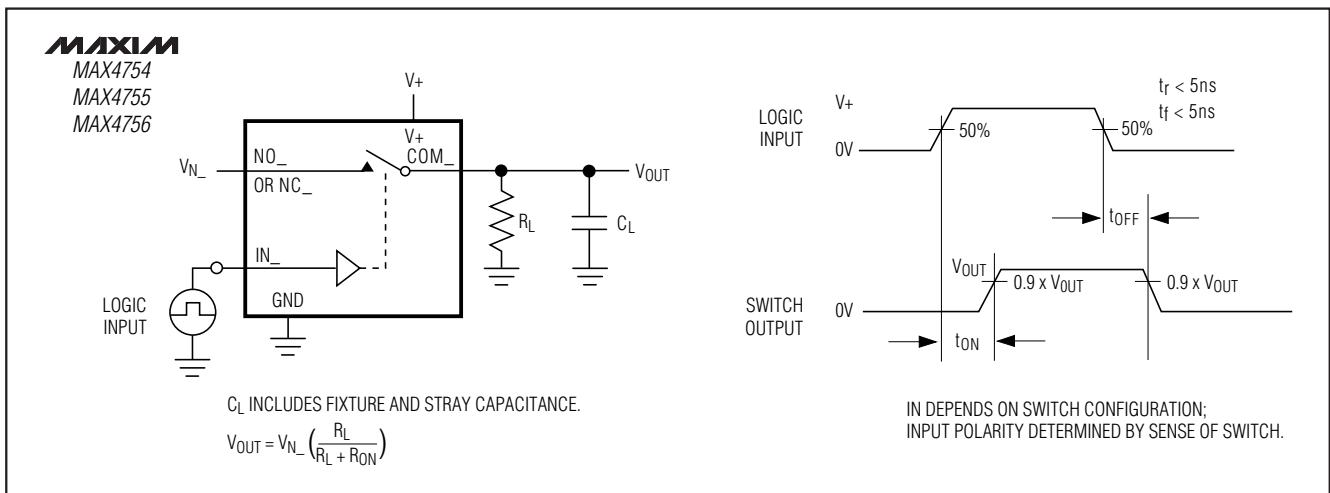


图 1. 开关时间

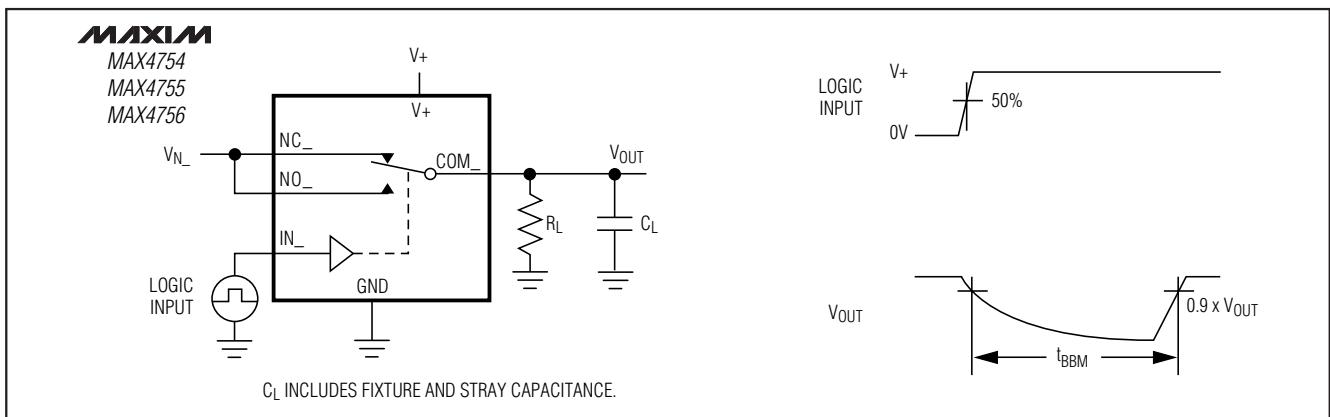


图 2. 先断后合的间隔

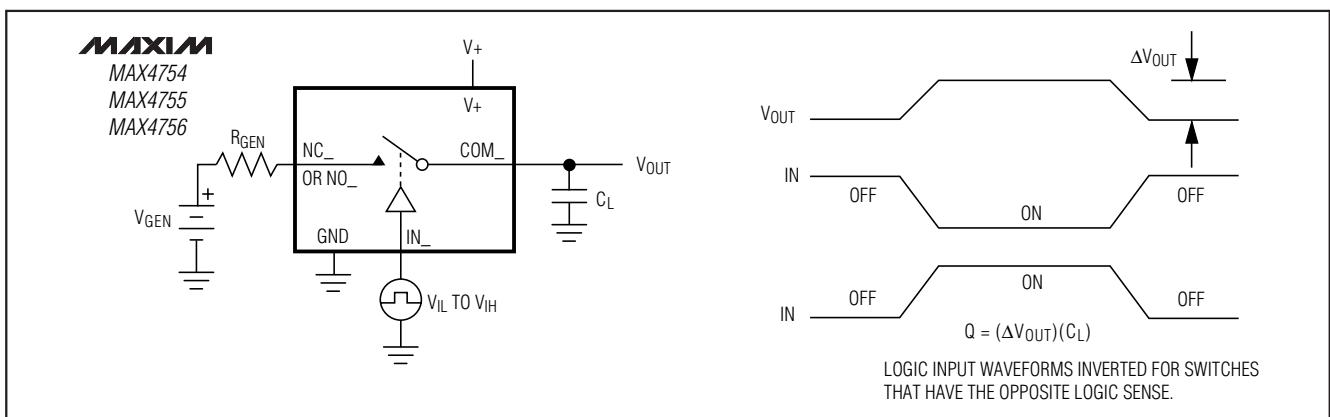


图 3. 电荷注入

# 0.5Ω、四路SPDT开关，UCSP/QFN封装

测试电路/时序图(续)

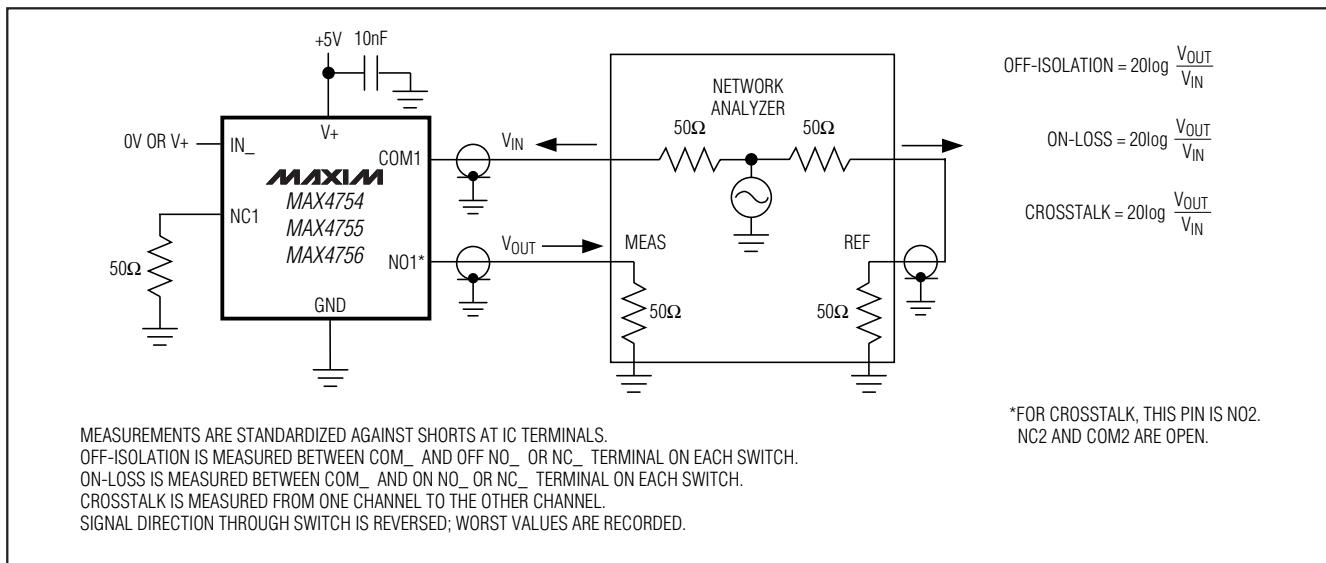


图 4. 导通损耗、关断隔离和串扰

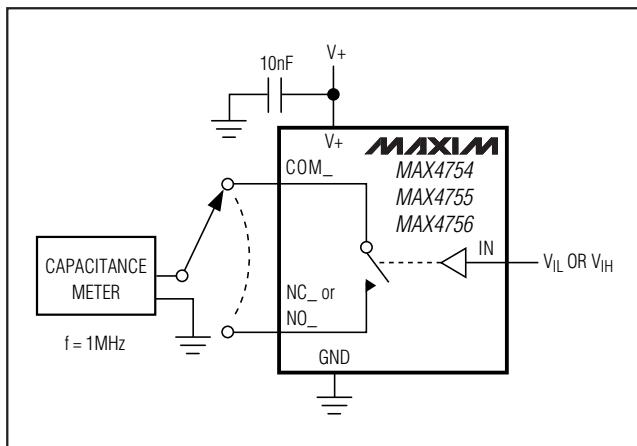


图 5. 通道开/关电容

## 引脚配置/真值表

TOP VIEW (BUMP SIDE DOWN)				引脚配置/真值表												
				THIN QFN												
<b>MAX4754/MAX4755/MAX4756</b>				<b>MAX4754/MAX4755/MAX4756</b>												
A	NC1	NO4	COM4	NC3	COM3	GND	NO3	1	16	15	14	13	12	11	10	9
B	COM1	V+	INB (EN)	NO2	NC2	COM2	NO2	2	15	14	13	12	11	10	9	8
C	NO1	INA	GND	COM2	NC2	INB (EN)	NO2	3	MAX4754	MAX4755	MAX4756	NC2	COM2	INB (EN)	NO2	
D	NC3	COM3	NO3	NC2	NO4	V+	COM4	4	5	6	7	8	5	6	7	8
() FOR MAX4756. UCSP				NOTE: EXPOSED PADDLE CONNECTED TO GND.												
<b>MAX4754/MAX4755</b>				<b>MAX4756</b>												
INA	NO1/NO2	NC1/NC2	NO3/NO4	NC3/NC4	EN	INA	NO_	NC_	LOW	LOW	OFF	ON	LOW	HIGH	ON	OFF
LOW	OFF	ON	—	—	LOW	HIGH	ON	OFF	HIGH	X	OFF	OFF	HIGH	X	OFF	OFF
HIGH	ON	OFF	—	—	HIGH	X	OFF	OFF	HIGH	X	OFF	OFF	HIGH	X	OFF	OFF
INB																
LOW	—	—	OFF	ON												
HIGH	—	—	ON	OFF												

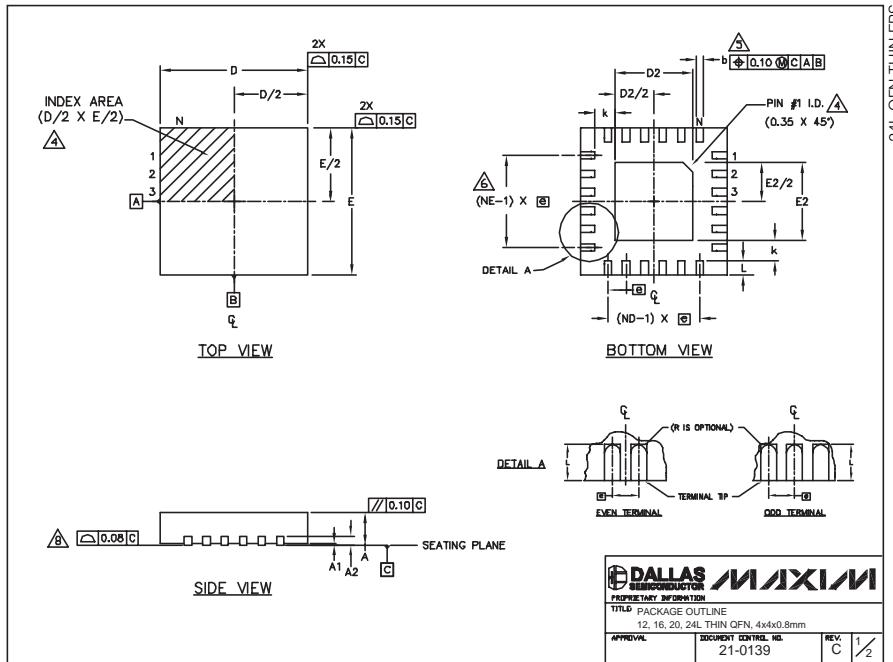
## 芯片信息

TRANSISTOR COUNT: 496

PROCESS: CMOS

# 0.5Ω、四路SPDT开关，UCSP/QFN封装

封装信息

(本数据资料提供的封装图可能不是最近的规格，如需最近的封装外型信息，请查询 [www.maxim-ic.com.cn/packages](http://www.maxim-ic.com.cn/packages)。)

COMMON DIMENSIONS										EXPOSED PAD VARIATIONS									
PKG CODES	12L 4x4			16L 4x4			20L 4x4			24L 4x4			DE	EE	DOWN BONDS ALLOWED				
	MIN.	NDM	MAX.	MIN.	NDM	MAX.	MIN.	NDM	MAX.	MIN.	NDM	MAX.							
A	0.70	0.75	0.80	0.70	0.75	0.80	0.70	0.75	0.80	0.70	0.75	0.80							
A1	0.0	0.02	0.05	0.0	0.02	0.05	0.0	0.02	0.05	0.0	0.02	0.05							
A2	0.20	REF		0.20	REF		0.20	REF		0.20	REF								
b	0.25	0.30	0.35	0.25	0.30	0.35	0.20	0.25	0.30	0.18	0.23	0.30							
D	3.90	4.00	4.10	3.90	4.00	4.10	3.90	4.00	4.10	3.90	4.00	4.10							
E	3.90	4.00	4.10	3.90	4.00	4.10	3.90	4.00	4.10	3.90	4.00	4.10							
e	0.60	BSC.		0.65	BSC.		0.50	BSC.		0.50	BSC.								
k	0.25	-	-	0.25	-	-	0.25	-	-	0.25	-	-							
L	0.45	0.55	0.65	0.45	0.55	0.65	0.45	0.55	0.65	0.30	0.40	0.50							
N	12			16			20			24									
ND	3			4			5			6									
NE	3			4			5			6									
Vedec Var.	WGGB			WGBC			WGGB-1			WGDD-2									

## NOTES:

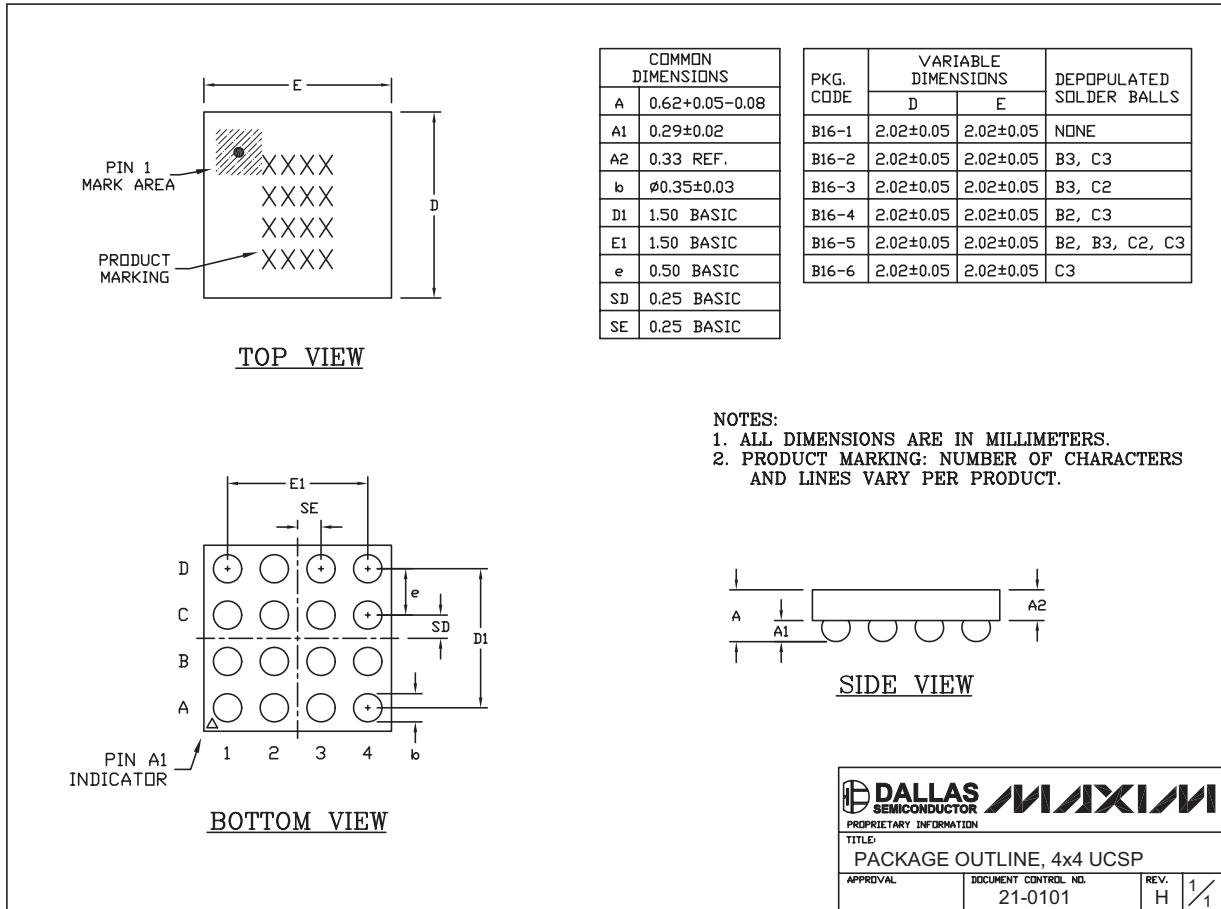
1. DIMENSIONING & TOLERANCING CONFORM TO ASME Y14.5M-1994.
2. ALL DIMENSIONS ARE IN MILLIMETERS. ANGLES ARE IN DEGREES.
3. N IS THE TOTAL NUMBER OF TERMINALS.
4. THE TERMINAL #1 IDENTIFIER AND TERMINAL NUMBERING CONVENTION SHALL CONFORM TO JEDEC JESD 95-1 SPP-012. DETAILS OF TERMINAL #1 IDENTIFIER ARE OPTIONAL, BUT MUST BE LOCATED WITHIN THE ZONE INDICATED. THE TERMINAL #1 IDENTIFIER MAY BE EITHER A MOLD OR MARKED FEATURE.
5. DIMENSION b APPLIES TO METALIZED TERMINAL AND IS MEASURED BETWEEN 0.25 mm AND 0.30 mm FROM TERMINAL TIP.
6. ND AND NE REFER TO THE NUMBER OF TERMINALS ON EACH D AND E SIDE RESPECTIVELY.
7. DEPOPULATION IS POSSIBLE IN A SYMMETRICAL FASHION.
8. COPLANARITY APPLIES TO THE EXPOSED HEAT SINK SLUG AS WELL AS THE TERMINALS.
9. DRAWING CONFORMS TO JEDEC MO220, EXCEPT FOR T2444-1, T2444-3 AND T2444-4.



# 0.5Ω、四路SPDT开关，UCSP/QFN封装

## 封装信息(续)

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16L-UCSP-EPS

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